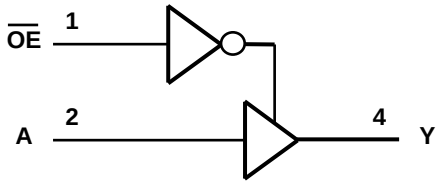
NEW PRODUCT

Pin Descriptions

Pin Name	Pin No.	Description
$\overline{OE}$	1	Output Enable
A	2	Data Input
GND	3	Ground
Y	4	Data Output
Vcc	5	Supply Voltage

Logic Diagram



Function Table

Inputs		Output
$\overline{OE}$	A	Y
L	H	H
L	L	L
H	X	Z

NEW PRODUCT

Absolute Maximum Ratings (Note 2)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V_{CC}	Supply Voltage Range	-0.5 to 6.5	V
V_I	Input Voltage Range	-0.5 to 6.5	V
V_O	Voltage applied to output in high or low state	-0.5 to V_{CC} +0.5	V
I_{IK}	Input Clamp Current V_I<0	-20	mA
I_{OK}	Output Clamp Current (V_O < 0 or V_O > V_{CC})	±20	mA
I_O	Continuous output current (V_O = 0 to V_{CC})	±25	mA
I_{CC}	Continuous current through V_{CC}	50	mA
I_{GND}	Continuous current through GND	-50	mA
T_J	Operating Junction Temperature	-40 to 150	°C
T_{STG}	Storage Temperature	-65 to 150	°C

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 3)

Symbol	Parameter		Min	Max	Unit
V_{CC}	Operating Voltage		2	5.5	V
V_{IH}	High-level Input Voltage	V_{CC} = 2V	1.5		V
		V_{CC} = 3V	2.1		
		V_{CC} = 5.5V	3.85		
V_{IL}	Low-level input voltage	V_{CC} = 2V		0.5	V
		V_{CC} = 3V		0.9	
		V_{CC} = 5.5V		1.65	
V_I	Input Voltage		0	5.5	V
V_O	Output Voltage		0	V_{CC}	V
I_{OH}	High-level output current	V_{CC} = 2V		-50	uA
		V_{CC} = 3.3V ± 0.3V		-4	mA
		V_{CC} = 5V ± 0.5V		-8	
I_{OL}	Low-level output current	V_{CC} = 2V		50	uA
		V_{CC} = 5V ± 0.5V		4	mA
		V_{CC} = 3V		8	
Δt/ΔV	Input transition rise or fall rate	V_{CC} = 3.3V ± 0.3V		100	ns/V
		V_{CC} = 5V ± 0.5V		20	
T_A	Operating free-air temperature		-40	125	ºC

Notes: 3. Unused inputs should be held at V_{CC} or Ground.

NEW PRODUCT

Electrical Characteristics

Symbol	Parameter	Test Conditions	V_{CC}	25°C			-40°C to 85°C		-40°C to 125°C		Unit
				Min	Typ.	Max	Min	Max	Min	Max	
V_{OH}	High Level Output Voltage	I_{OH} = -50µA	2V	1.9	2		1.9		1.9		V
			3V	2.9	3		2.9		2.9		
			4.5V	4.4	4.5		4.4		4.4		
		I_{OH} = -4mA	3V	2.58			2.48		2.40		
		I_{OH} = -8mA	4.5V	3.94			3.8		3.70		
V_{OL}	Low Level Output Voltage	I_{OL} = 50µA	2V			0.1		0.1		0.1	V
			3V			0.1		0.1		0.1	
			4.5V			0.1		0.1		0.1	
		I_{OL} = 4mA	3V			0.36		0.44		0.55	
		I_{OL} = 8mA	4.5V			0.36		0.44		0.55	
I_I	Input Current	V_I = 5.5V or GND	0 to 5.5V			± 0.1		± 1		± 2	µA
I_{OZ}	Z State Leakage Current	V_O =0 to 5.5V	5.5V			0.25		2.5		10	µA
I_{CC}	Supply Current	V_I = 5.5V or GND I_O=0	5.5V			1		10		40	µA
C_i	Input Capacitance	V_I = V_{CC} – or GND	5.5V		2.0	10		10		10	pF
θ_{JA}	Thermal Resistance Junction-to-Ambient	SOT25	(Note 4)		195						°C/W
		SOT353			430						
θ_{JC}	Thermal Resistance Junction-to-Case	SOT25	(Note 4)		58						°C/W
		SOT353			155						

Note: 4. Test conditions for SOT25, and SOT353: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

NEW PRODUCT

Switching Characteristics

V_{CC} = 3.3V ± 0.3 (see Figure 1)

Parameter	From (Input)	TO (OUTPUT)		25ºC			-40ºC to 85ºC		-40ºC to 125ºC		Unit
				Min	Typ.	Max	Min	Max	Min	Max	
t_{pd}	A	Y	C_L=15pF	0.6	4.7	8.0	0.6	9.5	0.6	11.5	ns
			C_L=50pF	0.6	6.6	11.5	0.6	13.0	0.6	14.5	ns
t_{en}	$\overline{OE}$	Y	C_L=15pF	0.6	5.0	8.0	0.6	9.5	0.6	10.5	ns
			C_L=50pF	0.6	6.9	11.5	0.6	13.0	0.6	14.5	ns
t_{dis}	$\overline{OE}$	Y	C_L=15pF	0.6	6.0	9.7	0.6	11.5	0.6	12.5	ns
			C_L=50pF	0.6	8.3	13.2	0.6	15.0	0.6	16.5	ns

V_{CC} = 5V ± 0.5V (see Figure 1)

Parameter	From (Input)	TO (OUTPUT)		25ºC			-40ºC to 85ºC		-40ºC to 125ºC		Unit
				Min	Typ.	Max	Min	Max	Min	Max	
t_{pd}	A	Y	C_L=15pF	0.6	3.4	5.5	0.6	6.5	0.6	7.0	ns
			C_L=50pF	0.6	4.8	7.5	0.6	8.5	0.6	9.5	ns
t_{en}	$\overline{OE}$	Y	C_L=15pF	0.6	3.6	5.1	0.6	6.0	0.6	6.5	ns
			C_L=50pF	0.6	6.5	11.4	0.6	13.0	0.6	14.5	ns
t_{dis}	$\overline{OE}$	Y	C_L=15pF	0.6	4.1	6.8	0.6	8.0	0.6	8.5	ns
			C_L=50pF	0.6	5.7	8.8	0.6	10.0	0.6	11.0	ns

Operating Characteristics

T_A = 25 ºC

Parameter		Test Conditions	V_{CC} = 5 V	Unit
			Typ.	
C_{pd}	Power dissipation capacitance	f = 1 MHz No Load	12	pF

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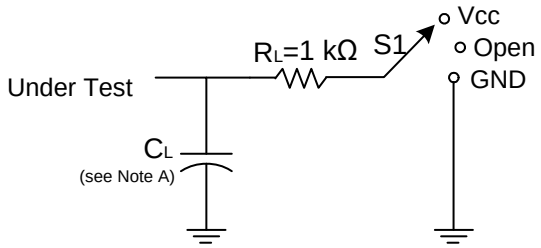
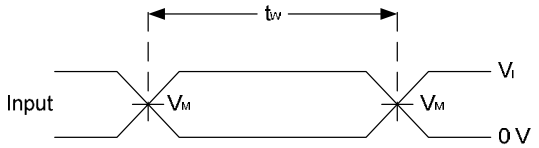
Parameter Measurement Information

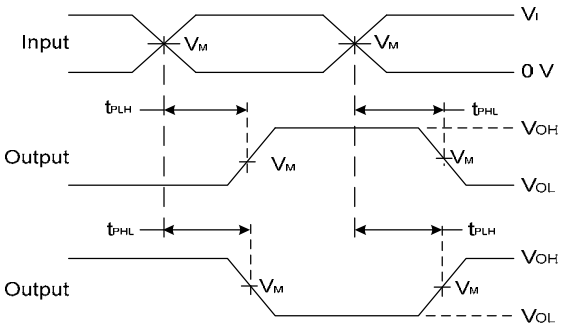


TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	Vload
t_{PHZ}/t_{PZH}	GND

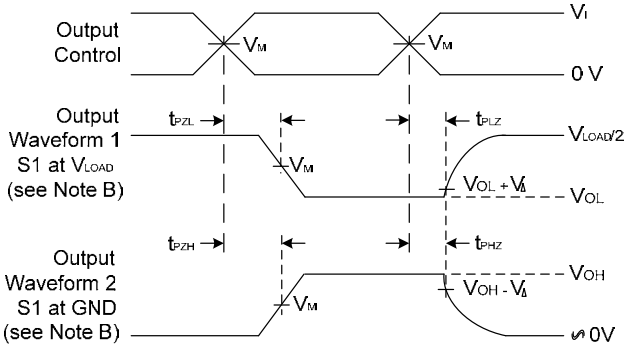
V_{CC}	Inputs		V_M	C_L	$V\Delta$
	V_I	t_r/t_f			
3.3V±0.3V	V_{CC}	≤3ns	$V_{CC}/2$	15pF	0.3V
5V±0.5V	V_{CC}	≤3ns	$V_{CC}/2$	15pF	0.3V
3.3V±0.3V	V_{CC}	≤3ns	$V_{CC}/2$	50pF	0.3V
5V±0.5V	V_{CC}	≤3ns	$V_{CC}/2$	50pF	0.3V



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs



Voltage Waveform Enable and Disable Times Low and High Level Enabling

Figure 1. Load Circuit and Voltage Waveforms

Notes:
A. Includes test lead and test apparatus capacitance.
B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.
C. Inputs are measured separately one transition per measurement.
D. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
E. t_{PZL} and t_{PZH} are the same as t_{EN}.
F. t_{PLH} and t_{PHL} are the same as t_{PD}.

NEW PRODUCT

Ordering Information

74 AHC 1G 125 XX - 7

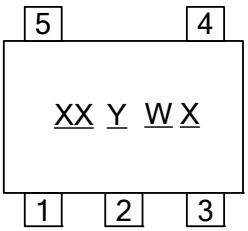
Logic Device	Function	Package	Packing
74 : Logic Prefix AHC : 2 to 5.5V Family 1G : One gate	125 : 3-State Buffer OE-Low	W5 : SOT25 SE : SOT353	7 : Tape & Reel

Device	Package Code	Packaging (Note 5)	7" Tape and Reel	
			Quantity	Part Number Suffix
74AHC1G125W5-7	W5	SOT25	3000/Tape & Reel	-7
74AHC1G125SE-7	SE	SOT353	3000/Tape & Reel	-7

Notes: 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

Marking Information

(Top View)



XX : Identification code
Y : Year 0~9
W : Week : A~Z : 1~26 week; a~z : 27~52 week; z represents 52 and 53 week
X : A~Z : Internal code

Part Number	Package	Identification Code
74AHC1G125W5	SOT25	YY
74AHC1G125SE	SOT353	YY

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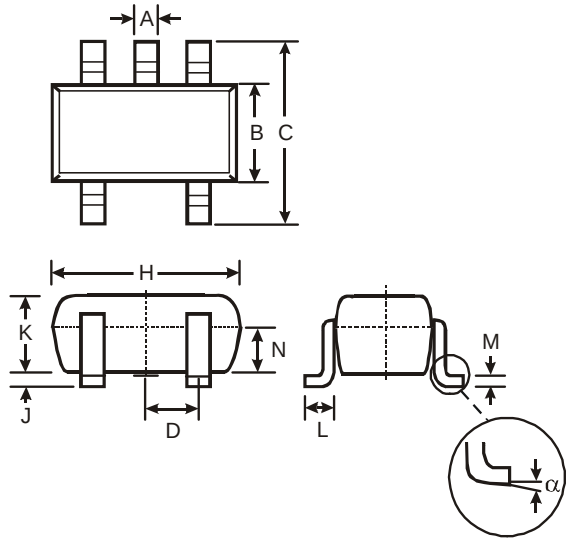
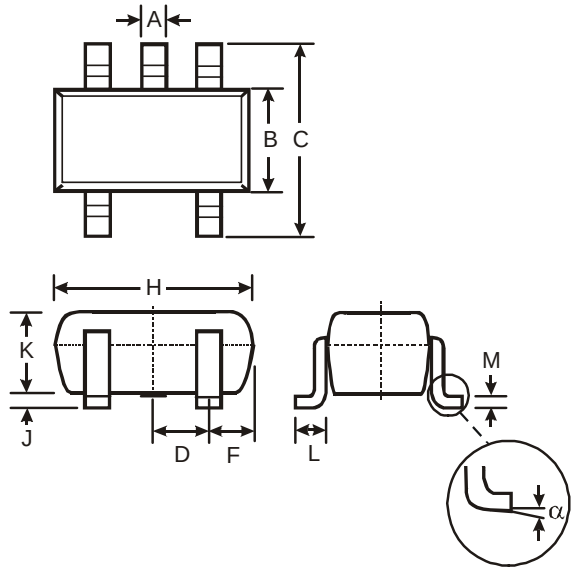
Package Outline Dimensions (All Dimensions in mm)

(1) Package Type: SOT25



SOT25			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
N	0.70	0.80	0.75
α	0°	8°	—
All Dimensions in mm			

(2) Package Type: SOT353



SOT353		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Typ	
F	0.40	0.45
H	1.80	2.20
J	0	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.22
α	0°	8°
All Dimensions in mm		

NEW PRODUCT

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